

## AD8353ACPZ-REEL7

## RF Amp Single Gain Amp 2.7GHz 5.5V 8-Pin LFCSP EP T/R

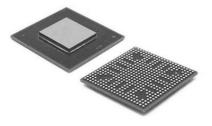
Manufacturer: Analog Devices, Inc

Package/Case: LFCSP-8

**Product Type:** Amplifier ICs

RoHS: RoHS Compliant/Lead free

Lifecycle: Active



Images are for reference only

Inquiry

## **General Description**

The AD8353 is a broadband, fixed-gain, linear amplifier that operates at frequencies from 1 MHz up to 2.7 GHz. It is intended for use in a wide variety of wireless devices, including cellular, broadband, CATV, and LMDS/MMDS applications.

By taking advantage of ADI's high performance, complementary Si bipolar process, these gain blocks provide excellent stability over process, temperature, and power supply. This amplifier is single-ended and internally matched to  $50~\Omega$  with a return loss of greater than 10~dB over the full operating frequency range.

The AD8353 provides linear output power of 9 dBm with 20 dB of gain at 900 MHz when biased at 3 V and an external RF choke is connected between the power supply and the output pin. The dc supply current is 42 mA. At 900 MHz, the output third-order intercept (OIP3) is greater than 23 dBm and is 19 dBm at 2.7 GHz.

The noise figure is 5.3 dB at 900 MHz. The reverse isolation (S12) is -36 dB at 900 MHz and -30 dB at 2.7 GHz.

The AD8353 can also operate with a 5 V power supply; in which case, no external inductor is required. Under these conditions, the AD8353 delivers 8 dBm with 20 dB of gain at 900 MHz. The dc supply current is 42 mA. At 900 MHz, the OIP3 is greater than 22 dBm and is 19 dBm at 2.7 GHz. The noise figure is 5.6 dB at 900 MHz. The reverse isolation (S12) is -35 dB.

The AD8353 is fabricated on ADI's proprietary, high performance, 25 GHz, Si complementary, bipolar IC process. The AD8353 is available in a chip scale package that uses an exposed paddle for excellent thermal impedance and low impedance electrical connection to ground. It operates over a -40°C to +85°C temperature range, and an evaluation board is also available.

Key Features Application

Fixed gain of 20 dB VCO buffers

Operational frequency of 1 MHz to 2.7 GHz

General Tx/Rx amplification

Linear output power up to 9 dBm

Power amplifier predrivers

Temperature and power supply stable

Low power antenna drivers

Input/output internally matched to 50  $\Omega$ 

Power supply: 3 V or 5 V

Noise figure: 5.3 dB

AVAQ SEMICONDUCTOR CO., LIMITED

## Recommended For You

ADF4153BCPZ

Analog Devices, Inc

QFN

AD6620ASZ

Analog Devices, Inc

QFP

AD8319ACPZ

Analog Devices, Inc

LFCSP

AD608AR

Analog Devices, Inc

SOP16

AD8317ACPZ

Analog Devices, Inc

LFCSP

ADF5355BCPZ

Analog Devices, Inc

LFCSP32

ADF4107BCPZ

Analog Devices, Inc

QFN

ADRF6755ACPZ

Analog Devices, Inc

QFN

ADF4107BRUZ-REEL7

Analog Devices, Inc

TSSOP16

AD608ARZ

Analog Devices, Inc

SOP16

AD8318ACPZ

Analog Devices, Inc

LFCSP

ADL5513ACPZ-R7

Analog Devices, Inc

LFCSP-16

ADL5535ARKZ-R7

Analog Devices, Inc

SOT89

ADRF6780ACPZN

Analog Devices, Inc

QFN

AD8318ACPZ-REEL7

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LFCSP